

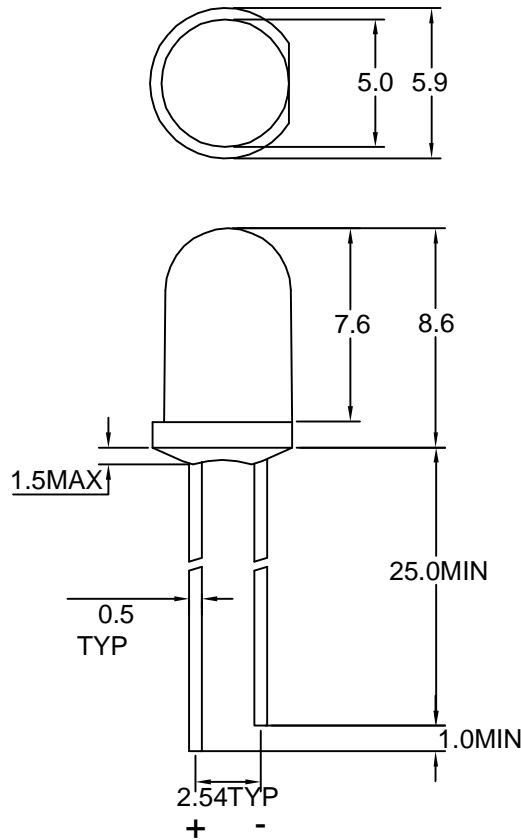
**ROUND TYPE LED LAMPS**

Lead-Free Parts

**LI3330/H0-PF****DATA SHEET**DOC. NO : QW0905-LI3330/H0-PF-08REV. : ADATE : 11 - Sep. - 2008

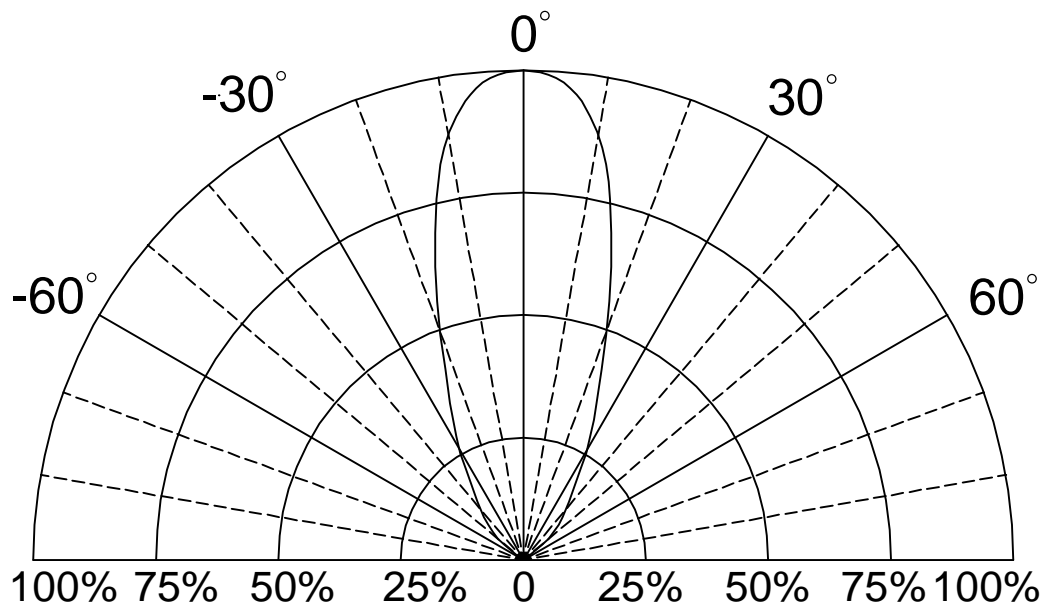


### Package Dimensions



Note : 1.All dimension are in millimeter tolerance is  $\pm 0.25\text{mm}$  unless otherwise noted.  
2.Specifications are subject to change without notice.

### Directivity Radiation



**Absolute Maximum Ratings at Ta=25 °C**

| Parameter                               | Symbol | Absolute Maximum Ratings |  | UNIT |
|---|--------|--------------------------|--|------|
|   |        | Orange                   |  |      |
| Forward Current                         | IF     | 15                       |  | mA   |
| Peak Forward Current<br>Duty 1/10@10KHz | IFP    | 50                       |  | mA   |
| Power Dissipation                       | PD     | 50                       |  | mW   |
| Reverse Current @5V                     | Ir     | 10                       |  | μA   |
| Operating Temperature                   | Topr   | -40 ~ +85                |  | °C   |
| Storage Temperature                     | Tstg   | -40 ~ +100               |  | °C   |

**Typical Electrical & Optical Characteristics (Ta=25 °C)**

| PART NO      | MATERIAL  | COLOR   |              | Peak wave length<br>λ Pnm | Spectral halfwidth<br>Δ λ nm | Forward voltage<br>@10mA(V) |      | Luminous intensity<br>@10mA(mcd) |      | Viewing angle<br>2θ 1/2<br>(deg) |
|--------------|-----------|---------|--------------|---------------------------|------------------------------|-----------------------------|------|----------------------------------|------|----------------------------------|
|              |           | Emitted | Lens         |                           |                              | Min.                        | Typ. | Min.                             | Typ. |                                  |
| LI3330/H0-PF | GaAsP/GaP | Orange  | Red Diffused | 635                       | 45                           | 1.7                         | 2.1  | 4.5                              | 8.0  | 40                               |

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.  
2. The luminous intensity data did not including ±15% testing tolerance.



### Typical Electro-Optical Characteristics Curve

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Fig.1 Forward current vs. Forward Voltage

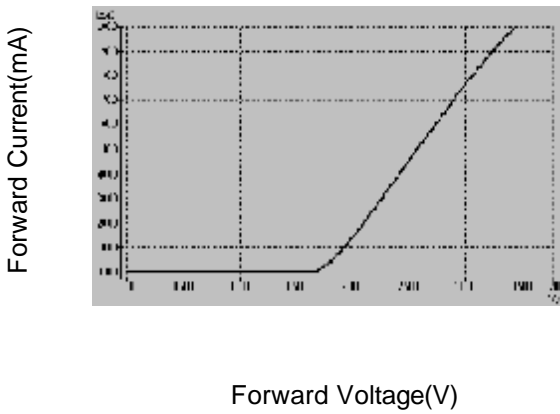


Fig.2 Relative Intensity vs. Forward Current

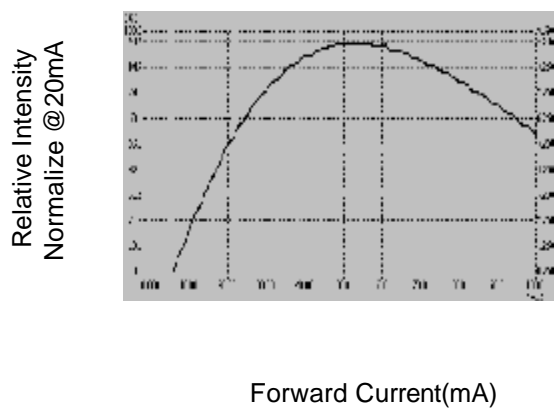


Fig.3 Forward Voltage vs. Temperature

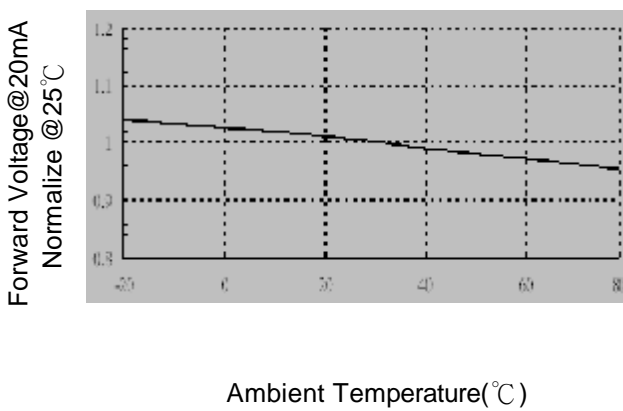


Fig.4 Relative Intensity vs. Temperature

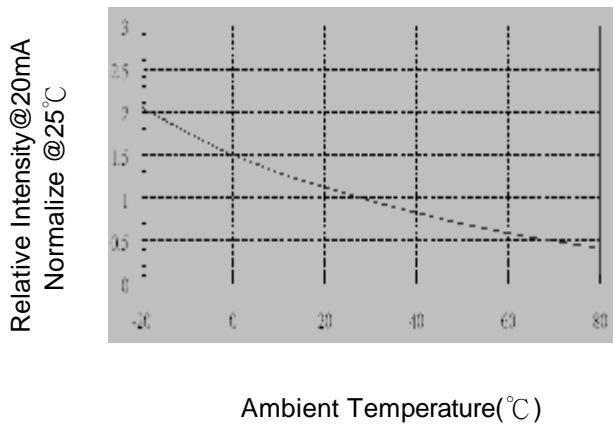
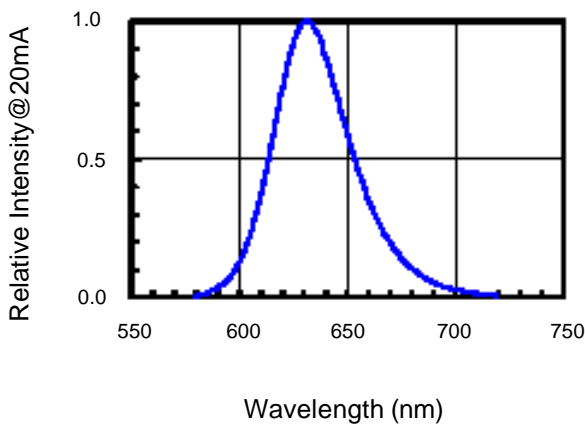


Fig.5 Relative Intensity vs. Wavelength





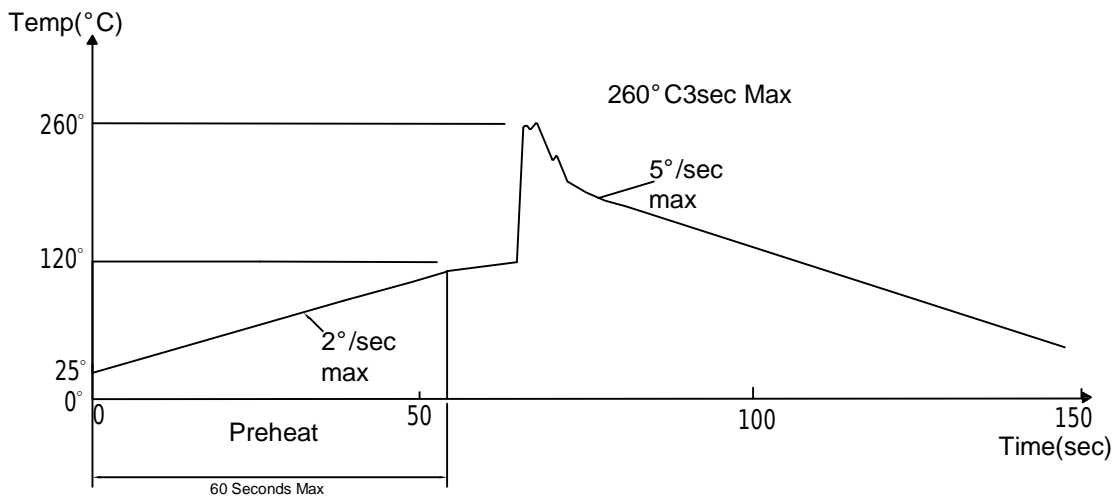
### Soldering Condition(Pb-Free)

#### 1.Iron:

- Soldering Iron:30W Max
- Temperature 350° C Max
- Soldering Time:3 Seconds Max(One Time)
- Distance:2mm Min(From solder joint to body)

#### 2.Wave Soldering Profile

- Dip Soldering
- Preheat: 120° C Max
- Preheat time: 60seconds Max
- Ramp-up
- 2° C/sec(max)
- Ramp-Down:-5° C/sec(max)
- Solder Bath:260° C Max
- Dipping Time:3 seconds Max
- Distance:2mm Min(From solder joint to body)



Note: 1.Wave solder should not be made more than one time.  
2.You can just only select one of the soldering conditions as above.



Reliability Test:

| Test Item                           | Test Condition   | Description   | Reference Standard   |
|-------------------------------------|--|---|--|
| Operating Life Test                 | 1.Under Room Temperature<br>2.If=20mA<br>3.t=1000 hrs (-24hrs, +72hrs) | This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.  | MIL-STD-750: 1026<br>MIL-STD-883: 1005<br>JIS C 7021: B-1                      |
| High Temperature Storage Test       | 1.Ta=105 °C±5°C<br>2.t=1000 hrs (-24hrs, +72hrs)                       | The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.  | MIL-STD-883:1008<br>JIS C 7021: B-10   |
| Low Temperature Storage Test        | 1.Ta=-40 °C±5°C<br>2.t=1000 hrs (-24hrs, +72hrs)                       | The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.   | JIS C 7021: B-12   |
| High Temperature High Humidity Test | 1.Ta=65 °C±5°C<br>2.RH=90 %~95%<br>3.t=240hrs ±2hrs                    | The purpose of this test is the resistance of the device under tropical for hours.  | MIL-STD-202:103B<br>JIS C 7021: B-11   |
| Thermal Shock Test                  | 1.Ta=105 °C±5°C & -40 °C±5°C (10min) (10min)<br>2.total 10 cycles      | The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.  | MIL-STD-202: 107D<br>MIL-STD-750: 1051<br>MIL-STD-883: 1011                    |
| Solder Resistance Test              | 1.T.Sol=260 °C±5°C<br>2.Dwell time= 10 ±1sec.                          | This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire. | MIL-STD-202: 210A<br>MIL-STD-750: 2031<br>JIS C 7021: A-1                      |
| Solderability Test                  | 1.T.Sol=230 °C±5°C<br>2.Dwell time=5 ±1sec                             | This test intended to see soldering well performed or not.  | MIL-STD-202: 208D<br>MIL-STD-750: 2026<br>MIL-STD-883: 2003<br>JIS C 7021: A-2 |